FZT953

100V PNP MEDIUM POWER TRANSISTOR IN SOT223

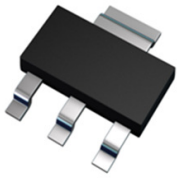
Features

- BV_{CEO} > -100V
- I_C = -5A High Continuous Collector Current
- I_{CM} = -10A Peak Pulse Current
- Low Saturation Voltage $V_{CE(sat)}$ < -115mV @ -1A
- $R_{CE(sat)}$ = 75mΩ for a Low Equivalent On-Resistance
- h_{FE} Specified up to -10A for a High Gain Hold-Up
- Complementary NPN Type: FZT853
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

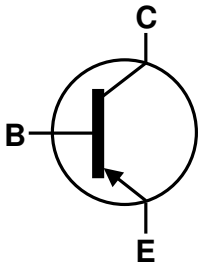
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.112 grams (Approximate)

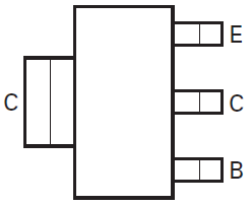
SOT223



Top View



Device Symbol



Top View
Pin-Out

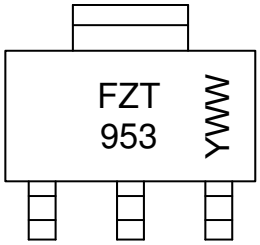
Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT953TA	AEC-Q101	FZT953	7	12	1,000
FZT953QTA	Automotive	FZT953	7	12	1,000

Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

SOT223



FZT 953 = Product Type Marking Code
YWW = Date Code Marking
Y or $\overline{Y}$ = Last Digit of Year (ex: 5= 2015)
WW or $\overline{WW}$ = Week Code (01~53)

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-140	V
Collector-Emitter Voltage	V_{CEO}	-100	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	I_C	-5	A
Peak Pulse Current	I_{CM}	-10	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

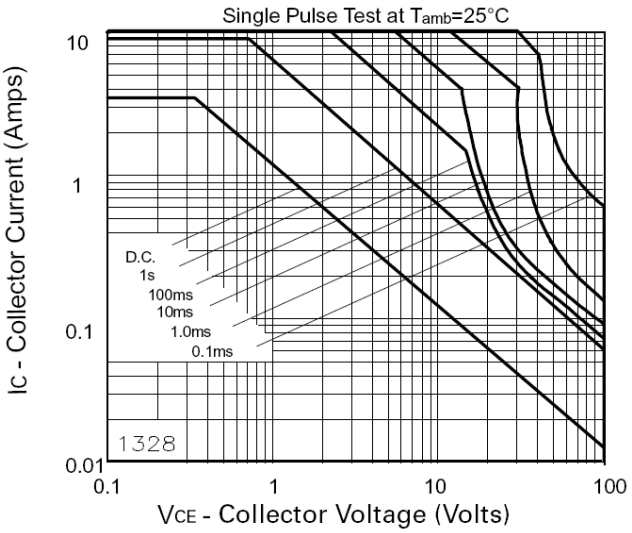
Characteristic		Symbol	Value	Unit
Power Dissipation Linear derating factor	(Note 6)	P_D	3.0 24	W mW /°C
	(Note 7)		1.6 12.8	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	42	°C/W
	(Note 7)	$R_{\theta JA}$	78	
Thermal Resistance Junction to Lead	(Note 8)	$R_{\theta JL}$	8.84	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

ESD Ratings (Note 9)

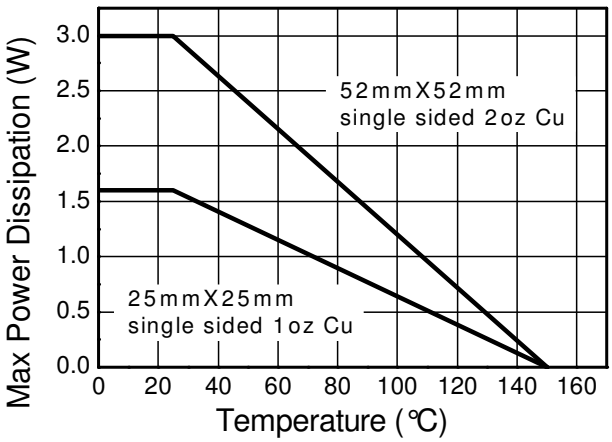
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	C

Notes:
6. For a device surface mounted on 52mm x 52mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
7. Same as Note 6, except the device is surface mounted on 25mm x 25mm with 1oz copper.
8. Thermal resistance from junction to solder-point (at the end of the collector lead).
9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

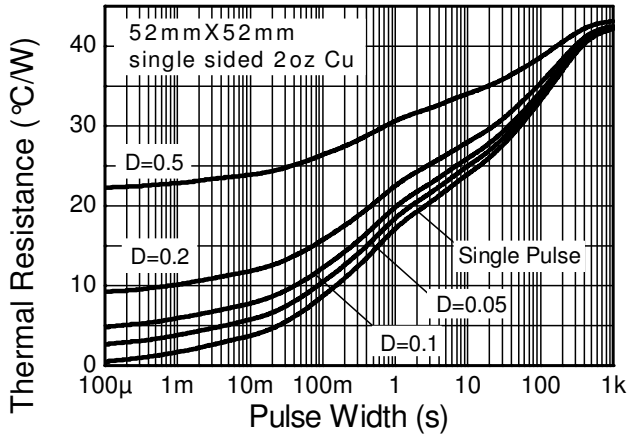
Thermal Characteristics and Derating Information



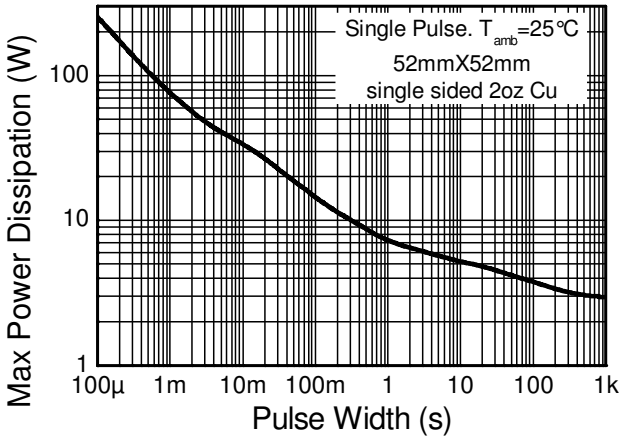
Safe Operating Area



Derating Curve



Transient Thermal Impedance



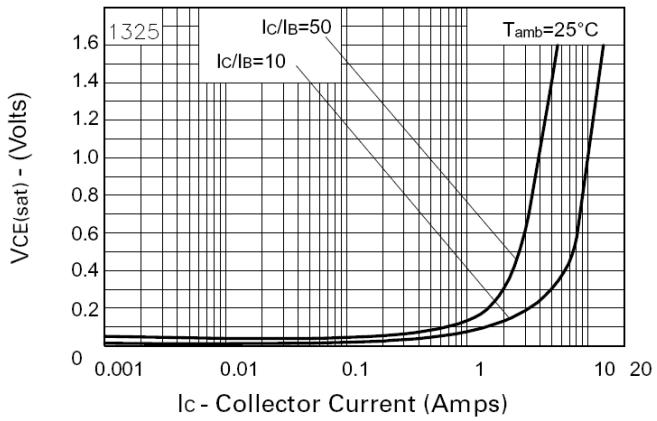
Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

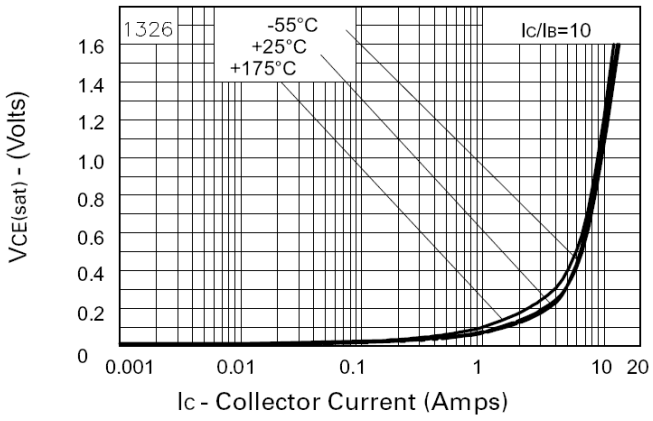
Characteristic	Symbol	Min	Typ.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	-140	-170	-	V	I_C = -100µA
Collector-Emitter Breakdown Voltage (Note 10)	BV_{CER}	-140	-170	-	V	I_C = -1µA, R_B ≤ 1kΩ
Collector-Emitter Breakdown Voltage (Note 10)	BV_{CEO}	-100	-120	-	V	I_C = -1mA
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	-8	-	V	I_E = -100µA
Collector Cutoff Current	I_{CBO}	- -	<1 -	-50 -1	nA µA	V_{CB} = -100V V_{CB} = -100V, T_A = +100°C
Collector Cutoff Current	I_{CER} R ≤1kΩ	- -	<1 -	-50 -1	nA µA	V_{CB} = -100V V_{CB} = -100V, T_A = +100°C
Emitter Cutoff Current	I_{EBO}	-	<1	-10	nA	V_{EB} = -6V
DC current transfer Static ratio (Note 10)	h_{FE}	100	200	-	-	I_C = -10mA, V_{CE} = -1V
		100	200	300		I_C = -1A, V_{CE} = -1V
		50	90	-		I_C = -3A, V_{CE} = -1V
		30	50	-		I_C = -4A, V_{CE} = -1V
		-	15	-		I_C = -10A, V_{CE} = -1V
Collector-Emitter Saturation Voltage (Note 10)	$V_{CE(sat)}$	-	-20	-50	mV	I_C = -100mA, I_B = -10mA
		-	-90	-115		I_C = -1A, I_B = -100mA
		-	-160	-220		I_C = -2A, I_B = -200mA
		-	-300	-420		I_C = -4A, I_B = -400mA
Base-Emitter Saturation Voltage (Note 10)	$V_{BE(sat)}$	-	-1,010	-1,170	mV	I_C = -4A, I_B = -400mA
Base-Emitter Turn-on Voltage (Note 10)	$V_{BE(on)}$	-	-925	-1,160	mV	I_C = -4A, V_{CE} = -1V
Transitional Frequency	f_T	-	125	-	MHz	I_C = -100mA, V_{CE} = -10V, f = 50MHz
Output capacitance	C_{obo}	-	65	-	pF	V_{CB} = -10V, f = 1MHz
Switching Time	t_{ON}	-	110	-	ns	V_{CC} = -10V, I_C = -2A, I_{B1} = -I_{B2} = -200mA
	t_{OFF}	-	460	-		

Note: 10. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

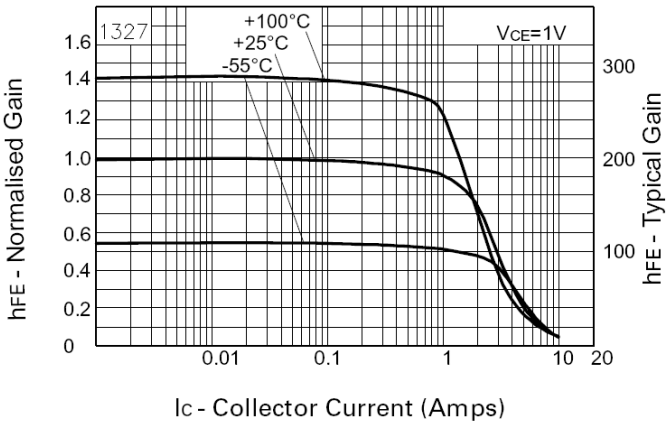
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



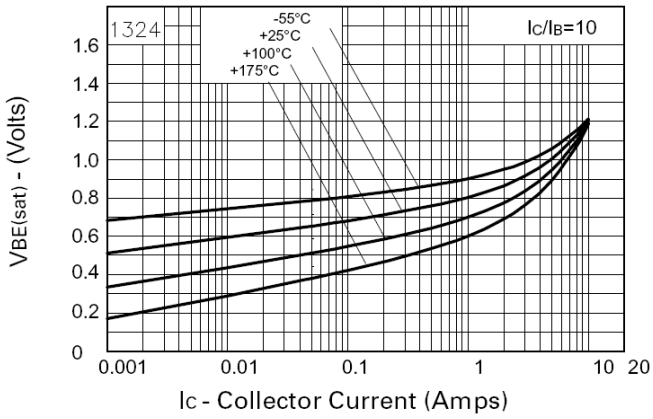
VCE(sat) v IC



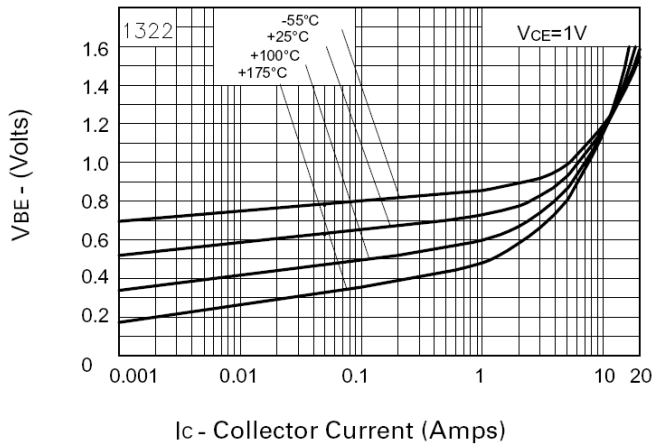
VCE(sat) v IC



hFE v IC



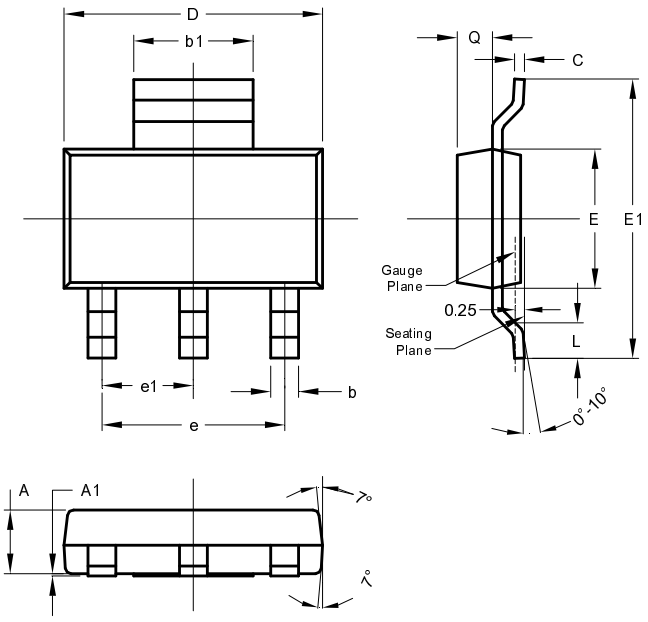
VBE(sat) v IC



VBE(on) v IC

Package Outline Dimensions

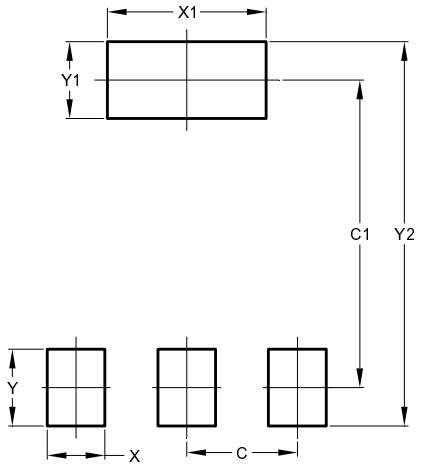
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223			
Dim	**Min**	**Max**	**Typ**
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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